

UNISONIC TECHNOLOGIES CO., LTD

BAW56 Preliminary DIODE

DUAL SURFACE MOUNT SWITCHING DIODE

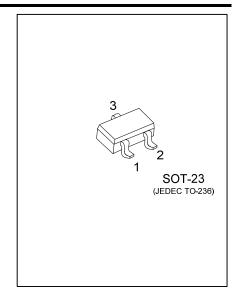
DESCRIPTION

The UTC **BAW56** is a dual surface mount switching diode providing the designers with ultra-fast switching and high conductance.

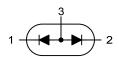
The UTC **BAW56** is suitable for general purpose switching applications.

■ FEATURES

- * Ultra-fast switching
- * Low switching loss
- * High Conductance



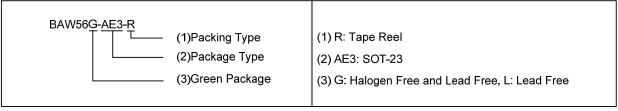
■ SYMBOL



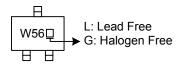
ORDERING INFORMATION

Ordering Number		Dealtons	Pin Assignment			Deelsing	
Lead Free	Halogen Free	Package	1	2	3	Packing	
BAW56L-AE3-R	BAW56G-AE3-R	SOT-23	K1	K2	A1A2	Tape Reel	

Note: Pin Assignment: A: Anode K: Cathode



■ MARKING



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■ ABSOLUTE MAXIMUM RATINGS (T_A=25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT	
Non-Repetitive Peak Reverse Voltage		V_{RM}	100	V	
Repetitive Peak Reverse Voltage		V_{RRM}	75	V	
Working Peak Reverse Voltage		V_{RWM}	75	V	
DC Blocking Voltage		V_R	75	V	
RMS Reverse Voltage		$V_{R(RMS)}$	53	V	
Forward Continuous Current (Note 2)	I_{FM}	300	mA		
Average Rectified Output Current	lo	150	mA		
Non Denetitive Book Forward Curse Current	t=1.0µs		2.0	Α	
Non-Repetitive Peak Forward Surge Current	t=1.0s	I _{FSM}	1.0		
Power Dissipation (Note 2)		P_D	350	mW	
Junction Temperature	TJ	-65 ~ +150	°C		
Storage Temperature		T _{STG}	-65 ~ +150	°C	

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT	
Junction to Ambient (Note 2)	θ_{JA}	357	°C/W	

■ **ELECTRICAL CHARACTERISTICS** (T_A =25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Reverse Breakdown Voltage	$V_{BR(R)}$	I _R = 2.5µA	75			V
Forward Voltage (Note 1, 3)	V _F	I _F = 1.0mA			0.715	V
		I _F = 10mA			0.855	V
		$I_F = 50mA$			1.0	V
		I _F = 150mA			1.25	V
Peak Reverse Current (Note 1)	I _R	V _R = 75V			2.5	μΑ
		V _R = 75V, T _J = 150°C			50	μΑ
		V _R = 25V, T _J = 150°C			30	μΑ
		V _R = 20V			25	nA
Junction Capacitance	CJ	$V_R = 0$, $f = 1.0MHz$			2.0	pF
Reverse Recovery Time	t _{rr}	$I_F = I_R = 10 \text{mA}, I_{RR} = 0.1 \text{ x } I_R,$ $R_L = 100 \Omega$			4.0	ns

Notes: 1. Short duration test pulse used to minimize self-heating effect.

- 2. Part mounted on FR-4 PC board with recommended pad layout.
- 3. Pulse Test: Pulse Width: 300µs, Duty Cycle ≤ 2%.

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